TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LCX08F, TC74LCX08FN, TC74LCX08FT

LOW-VOLTAGE QUAD 2-INPUT AND GATE WITH 5V TOLERANT INPUTS AND OUTPUTS

The TC74LCX08 is a high performance CMOS 2-INPUT AND GATE. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3V) V_{CC} applications, but it could be used to interface to 5V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

FEATURES

Low voltage operation : V_{CC} = 2.0~3.6V

• High speed operation : $t_{pd} = 5.5$ ns (Max.) at $V_{CC} = 3.0 \sim 3.6$ V

Output current : |I_{OH}| / I_{OL} = 24mA (Min.) at V_{CC} = 3.0V

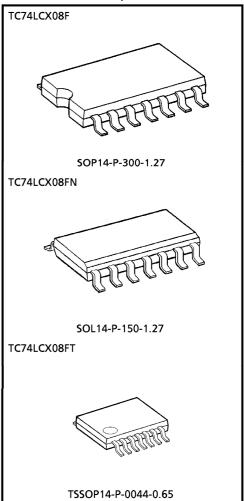
Latch-up performance : ±500mA

Available in JEDEC SOP, JEITA SOP and TSSOP

Power down protection is provided on all inputs and outputs.

 Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 08 type.

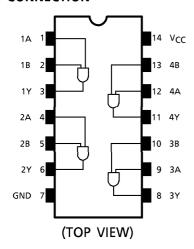
(Note) The JEDEC SOP (FN) is not available in Japan.



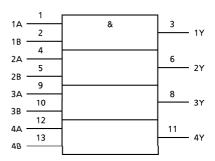
Weight

SOP14-P-300-1.27 : 0.18g (Typ.) SOL14-P-150-1.27 : 0.12g (Typ.) TSSOP14-P-0044-0.65 : 0.06g (Typ.)

PIN CONNECTION



IEC LOGIC SYMBOL



TRUTH TABLE

INP	UTS	OUTPUTS		
Α	В	Υ		
L	L	L		
L	Н	L		
Н	L	L		
Н	Н	Н		

MAXIMUM RATINGS

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PARAMETER	SYMBOL	RATING	UNIT	
Power Supply Voltage	Vcc	-0.5~7.0	V	
DC Input Voltage	VIN	-0.5~7.0	V	
DC Output Voltage	\/ - -	-0.5~7.0 (Note 1)	V	
DC Output Voltage	Vout	-0.5~V _{CC} +0.5 (Note 2)		
Input Diode Current	ΙΚ	– 50	mA	
Output Diode Current	loк	± 50 (Note 3)	mA	
DC Output Current	IOUT	± 50	mΑ	
Power Dissipation	PD	180	mW	
DC V _{CC} / Ground Current	ICC / IGND	± 100	mA	
Storage Temperature	T _{stg}	-65∼150	°C	

(Note 1) $V_{CC} = 0V$

(Note 2) High or Low State. IOUT absolute maximum rating must be observed.

(Note 3) V_{OUT} <GND, V_{OUT} > V_{CC}

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Valtage	V	2.0~3.6	V
Supply Voltage	VCC	1.5~3.6 (Note 4)	V
Input Voltage	V _{IN}	0~5.5	V
Output Valtage	V _{OUT}	0~5.5 (Note 5)	V
Output Voltage		0~ V _{CC} (Note 6)] '
Output Current	Jan./Jan	± 24 (Note 7)	A
Output Current	OH/IOL	± 12 (Note 8)	mA
Operating Temperature	T _{opr}	- 40∼85	°C
Input Rise And Fall Time	dt/dv	0~10 (Note 9)	ns / V

(Note 4) Data Retention Only

(Note 5) $V_{CC} = 0V$

(Note 6) High or Low State

(Note 7) $V_{CC} = 3.0 \sim 3.6 V$

(Note 8) $V_{CC} = 2.7 \sim 3.0 \text{V}$

(Note 9) $V_{IN} = 0.8 \sim 2.0 \text{V}$, $V_{CC} = 3.0 \text{V}$

ELECTRICAL CHARACTERISTICS

DC CHARACTERISTICS ($Ta = -40 \sim 85^{\circ}C$)

CHARA	CTERISTIC	SYMBOL	TEST	CONDITION	V _{CC} (V)	MIN.	MAX.	UNIT
Input	"H" Level	VIH			2.7~3.6	2.0	_	V
Voltage	"L" Level	V_{IL}			2.7~3.6	_	0.8	V
			I _{OH} = -100μA	2.7~3.6	V _{CC} - 0.2	_		
	"H" Level	Voн	V _{IN} = V _{IH}	I _{OH} = - 12mA	2.7	2.2	_	V
Output				I _{OH} = - 18mA	3.0	2.4	_	
Voltage				I _{OH} = -24mA	3.0	2.2	_	
"L" Level		V _{OL}		I _{OL} = 100μA	2.7~3.6		0.2	
	#1 # 1 aval		V _{IN} =	I _{OL} = 12mA	2.7	_	0.4	v
	L Levei		V _{IH} or V _{IL}	I _{OL} = 16mA	3.0		0.4	V
				I _{OL} = 24mA	3.0		0.55	
Input Leak	age Current	IN	V _{IN} = 0~5.5V		2.7~3.6		± 5.0	μΑ
Power Off Current	Leakage	lOFF	V _{IN} / V _{OUT} = 5.5V		0	-	10.0	μΑ
Quiescent S	Supply	•	V _{IN} = V _{CC} or GND V _{IN} / V _{OUT} = 3.6~5.5V		2.7~3.6		10.0	
Current		lcc			2.7~3.6		± 10.0	μ A
Increase In Input	ICC Per	ΔΙςς	V _{IH} = V _{CC} - 0.6V		2.7~3.6	I	500	μΑ

AC CHARACTERISTICS ($Ta = -40 \sim 85$ °C)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	MIN.	MAX.	UNIT
Propagation Delay	^t pLH	(Fig.1, 2)	2.7		6.2	nc
Time	^t pHL	(Fig. 1, 2)	3.3 ± 0.3	1.5	5.5	ns
Output To Output	t _{osLH}	(Note 10)	2.7	_	_	nc
Skew	^t osHL	(Note 10)	3.3 ± 0.3		1.0	ns

(Note 10) Parameter guaranteed by design. $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, \ t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

DYNAMIC SWITCHING CHARACTERISTICS (Ta = 25°C, Input $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500\Omega$)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP	UNIT
Quiet Output Maximum Dynamic VOL	V _{OLP}	V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V
Quiet Output Minimum Dynamic VOL	V _{OL} V	V _{IH} = 3.3V, V _{IL} = 0V	3.3	8.0	V

CAPACITIVE CHARACTERISTICS ($Ta = 25^{\circ}C$)

PARAMETER	SYMBOL	TEST CONDITION		V _{CC} (V)	TYP.	UNIT
Input Capacitance	C _{IN}			3.3	7	рF
Output Capacitance	COUT	-		0	8	рF
Power Dissipation Capacitance	C _{PD}	f _{IN} = 10MHz	(Note 11)	3.3	25	pF

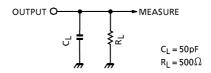
(Note 11) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

I_{CC} (opr.) = C_{PD}·V_{CC}·f_{IN} + I_{CC}/4 (Per gate)

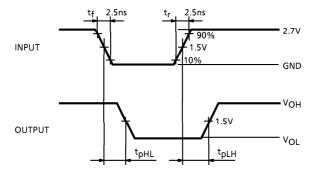
TEST CIRCUIT

Fig.1



AC WAVEFORM

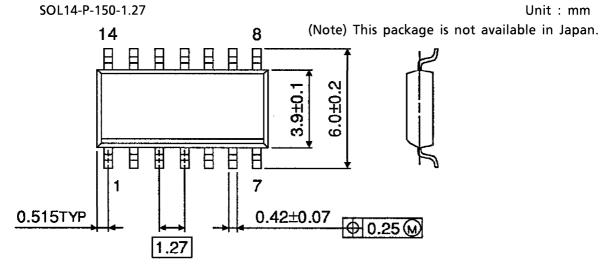
Fig.2 t_{pLH}, t_{pHL}

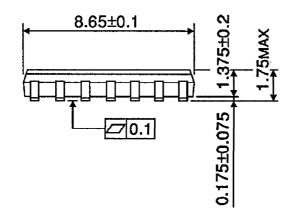


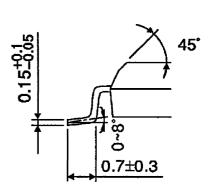
PACKAGE DIMENSIONS SOP14-P-300-1.27 $\mathsf{Unit}: \, \mathsf{mm}$ 14 8 5.3±0.2 7.8±0.3 (300mil) 7.62 7 0.43±0.1 0.25 W 1.34TYP 1.27 10.8MAX 10.3±0.2 **□** 0.1 0.8±0.2

Weight: 0.18g (Typ.)

PACKAGE DIMENSIONS





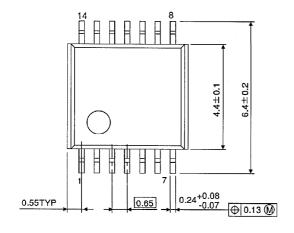


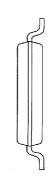
Weight: 0.12g (Typ.)

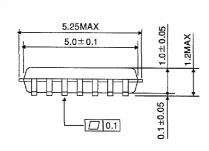
PACKAGE DIMENSIONS

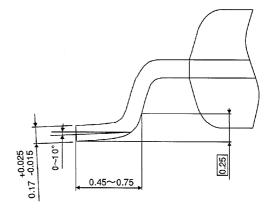
TSSOP14-P-0044-0.65

Unit: mm









Weight: 0.06g (Typ.)

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